



(2-92)

Sheet 1 of 1

Form PTO-1449			Docket Number (Optional) 3255.1US (91-507.1-RE)		Application Number 09/488,099		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)			Applicant Dennison et al.				
			Filing Date January 18, 2000		Group Art Unit 2822		
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
W	4,617,193	10/1986	Wu				
	4,714,686	12/1987	Sander et al.				
	4,868,138	09/1989	Chan et al.				
	4,892,845	01/1990	Bridges				
	5,110,766	05/1992	Maeda et al.				
	5,124,280	06/1992	Wei et al.				
	5,158,910	10/1992	Cooper et al.				
W	5,171,713	12/1992	Matthews				
FOREIGN PATENT DOCUMENTS							
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES NO	
W	41 07 883	09/1991	DE			X	
W	62-32630	02/1987	JP			X	
W	64-72543	03/1989	JP			X	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)							
W		Yoshire Nakata et al., "Tunnel Shape Stacked Capacitor (TSSC) Memory Cell for 64Mb Dram", article (date unknown).					
EXAMINER H. P. ...			DATE CONSIDERED 3/30/05				
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.							

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